

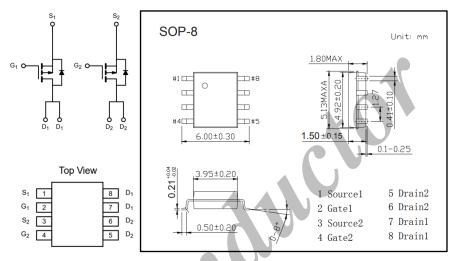
30V Dual P-Channel Enhancement Mode MOSFET

• General Description

AP4953DY combines advanced MOSFET technology with a low resistance package to provide extremely low $R_{DS(\text{ON})}$. This device is most suitable to load-switch or PWM applications.

Applications

- DC-DC converter for portable devices
- Load switch





Product Summary

V_{DS}	-30V
In (at $V_{GS} = -10V$)	-4.9A
$R_{DS(ON)}$ (at $V_{GS} = -10V$)	< 53mΩ
$R_{DS(ON)}$ (at $V_{GS} = -4.5V$)	< 95mΩ

• Absolute Maximum Ratings Ta = 25°C

Parameter	,	Symbol	Rating	Unit	
Drain-Source Voltage		V_{DS}	-30	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current	Ta = 25°C	I_D	-4.9		
	Ta = 70°C	1D	-3.9	A	
Pulsed Drain Current		I_{DM}	-30		
Power Dissipation	Ta = 25°C	P_D	2	W	
	Ta = 70°C	PD	1.3	VV	
Junction and Storage Temperature Range		T_J , T_{STG}	-55 to 150	°C	
Thermal Characteristics					
Thermal Resistance. Junction-to-Ambient	Steady State	$R_{ heta JA}$	62.5	°C/W	

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• Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Parameters						
Drain-Source Breakdown Voltage	V_{DSS}	I_D =-250 μ A, V_{GS} =0V	-30			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} =-30V, V_{GS} =0V			-1	μА
		V_{DS} =-30V, V_{GS} =0V, T_{J} =55°C		K	-25	
Gate-Body Leakage Current	I_{GSS}	V_{DS} =0V, V_{GS} =±20V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=-250\mu A$	-1		-3	V
On-State Drain Current	I _{D(ON)}	V_{GS} =-10V, V_{DS} =-5V	-20			Α
Static Drain-Source On-Resistance	D	V_{GS} =-10V, I_{D} =-4.9A	4 1	43	53	mΩ
	R _{DS(ON)}	V_{GS} =-4.5V, I_{D} =-3.6A		70	95	
Forward Transconductance	$\mathbf{g}_{ ext{FS}}$	V_{DS} =-5V, I_D =-6.5A	7	10		S
Diode Forward Voltage	V_{SD}	I _S =-1.7A, V _{GS} =0V			-1.2	V
Maximum Body-Diode Continuous Current	I_S				-1.7	A
Dynamic Parameters						
Total Gate Charge	Q_{g}			16	25	
Gate Source Charge	Q_{gs}	V_{GS} =-10V, V_{DS} =-15V, I_{D} =-4.9A		5		nC
Gate Drain Charge	Q_{gd}			2		
Gate Resistance	Rg		2		7.1	Ω
Turn-On Delay Time	t _{D(on)}			9	15	
Turn-On Rise Time	t _r	V_{GS} =-10V, V_{DS} =-15V, R_{L} =15 Ω ,		13	20	1
Turn-Off Delay Time	$t_{D(off)}$	$R_{GEN}=6\Omega$		25	40	ns
Turn-Off Fall Time	t_{f}			15	25	1
Body Diode Reverse Recovery Time	t_{rr}	I_F =-1.7A, d_i/d_t =100A/ μ s		60	90	

• Ordering Information

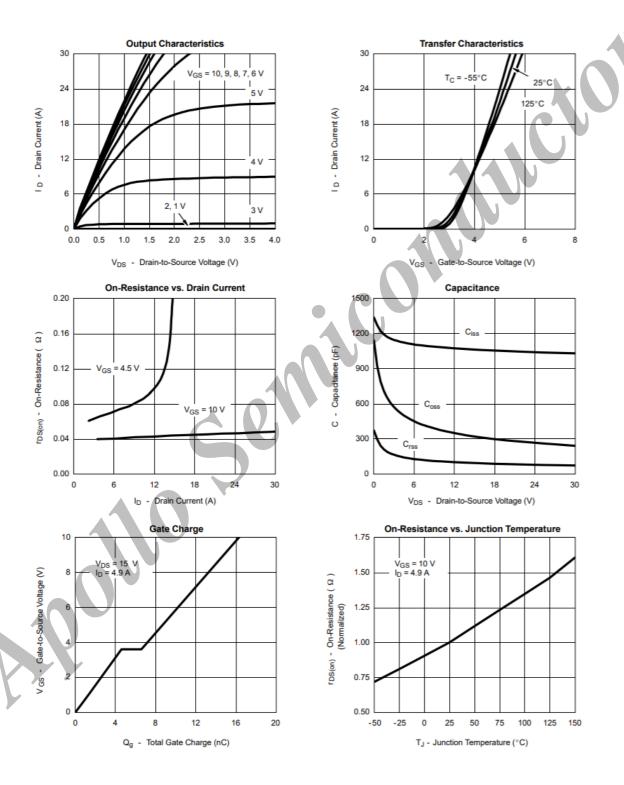
Ordering Part Number	Package	MOQ
AP4953DY	SOP-8	2,500 pcs / reel

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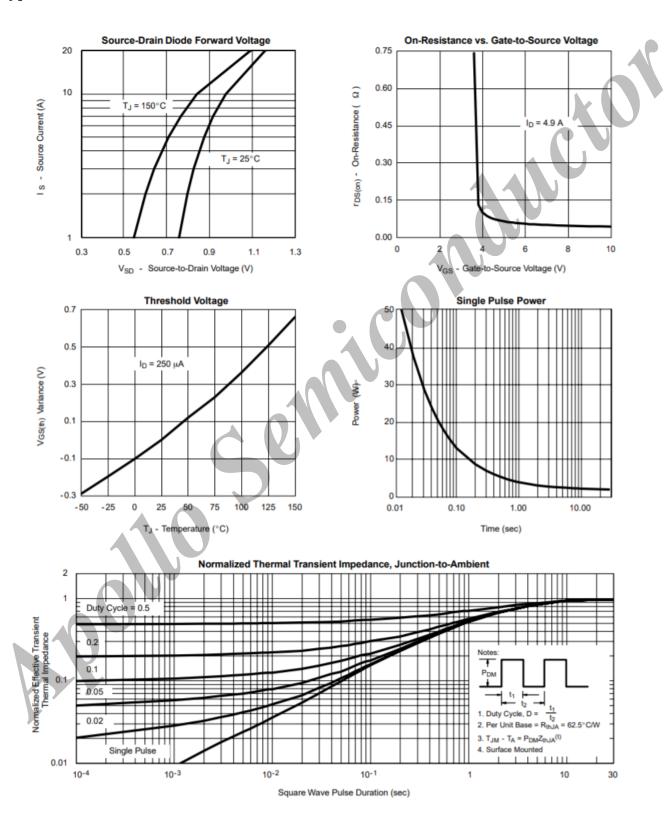
• Typical Electrical and Thermal Characteristics







• Typical Electrical and Thermal Characteristics





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